

1. General description

Planar passivated ultra sensitive gate Silicon Controlled Rectifier in a SOT54 (T0-92) plastic package.

2. Features and benefits

- Planar passivated for voltage ruggedness and reliability
- Ultra sensitive gate

3. Applications

- Electronic ballasts
- Safety shut down and protection circuits
- Sensing circuits
- Smoke detectors
- Switched Mode Power Supplies

4. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
V _{DRM}	repetitive peak off- state voltage		-	-	400	V
V _{RRM}	repetitive peak reverse voltage		-	-	400	V
I _{TSM}	non-repetitive peak on- state current	half sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 10 \text{ ms}; \text{Fig. 4}; \text{Fig. 5}$	-	-	8	A
I _{T(AV)}	average on-state current	half sine wave; T _{lead} ≤ 92 °C; <u>Fig. 1</u>	-	-	0.5	A
I _{T(RMS)}	RMS on-state current	half sine wave; T _{lead} ≤ 92 °C; <u>Fig. 2;</u> <u>Fig. 3</u>	-	-	0.8	A
Static chara	acteristics	· · · · · ·	I.			
I _{GT}	gate trigger current	V_D = 12 V; I _T = 10 mA; T _j = 25 °C; Fig. 7	-	3	12	μA

5. Pinning information

Table 2	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	А	anode		A H K
2	G	gate		Ġ sym037
3	К	cathode		
			TO-92 (SOT54)	

6. Ordering information

Table 3. Ordering information					
Type number	Package				
	Name	Description	Version		
EC103D1	TO-92	plastic single-ended leaded (through hole) package; 3 leads	SOT54		

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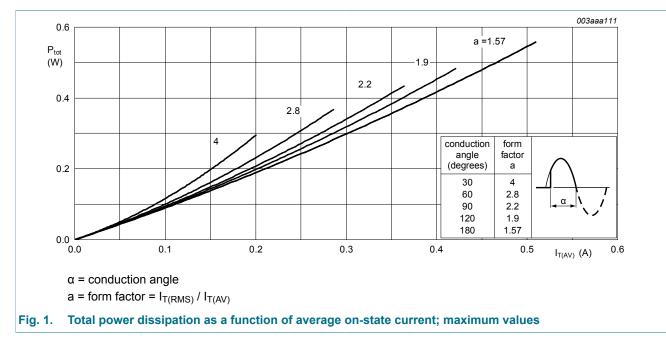
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7. Limiting values

Table 4.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

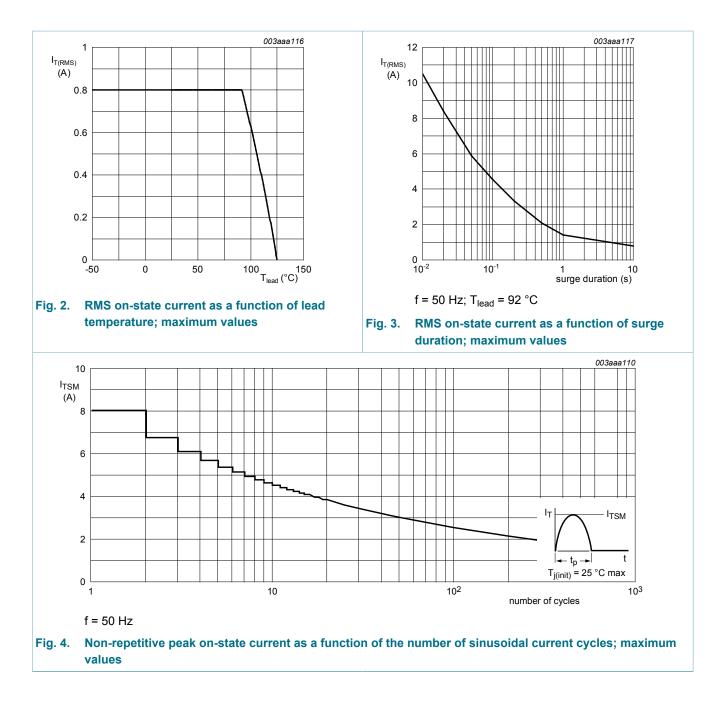
Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	400	V
V _{RRM}	repetitive peak reverse voltage		-	400	V
I _{T(AV)}	average on-state current	half sine wave; $T_{lead} \le 92 \text{ °C}$; Fig. 1	-	0.5	А
I _{T(RMS)}	RMS on-state current	half sine wave; $T_{lead} \le 92$ °C; Fig. 2; Fig. 3	-	0.8	А
I _{TSM}	non-repetitive peak on-state current	half sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 10 \text{ ms}; \text{ Fig. 4}; \text{ Fig. 5}$	-	8	A
		half sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 8.3 \text{ ms}$	-	9	A
l ² t	I ² t for fusing	t _p = 10 ms; SIN	-	0.32	A ² s
dl _T /dt	rate of rise of on-state current	$I_T = 2 \text{ A}; I_G = 10 \text{ mA}; \text{ d}I_G/\text{d}t = 100 \text{ mA}/$ µs	-	50	A/µs
I _{GM}	peak gate current		-	1	А
V _{RGM}	peak reverse gate voltage		-	5	V
P _{GM}	peak gate power		-	2	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.1	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	125	°C



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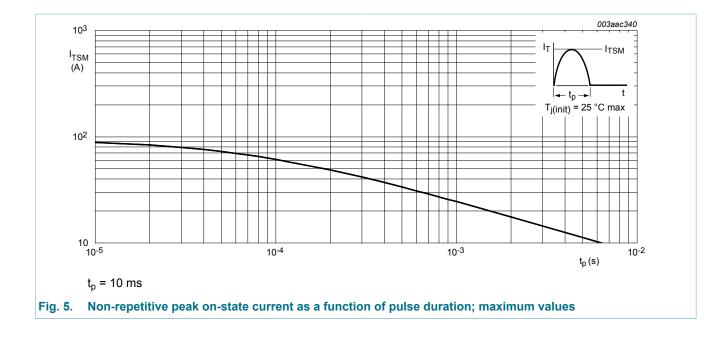
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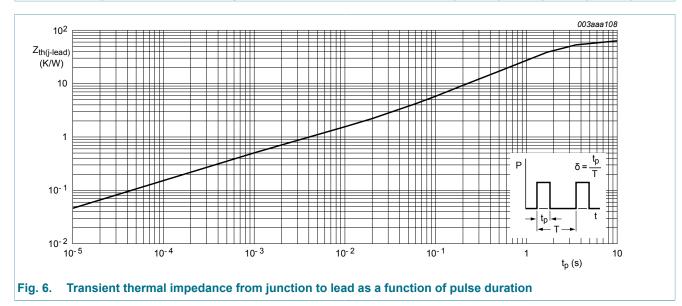


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8. Thermal characteristics

Table 5. Thermal characteristics							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-lead)}$	thermal resistance from junction to lead	Fig. 6		-	-	60	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	printed circuit board mounted: lead length = 4 mm		-	150	-	K/W



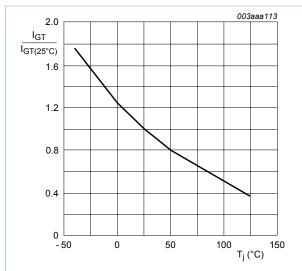
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9. Characteristics

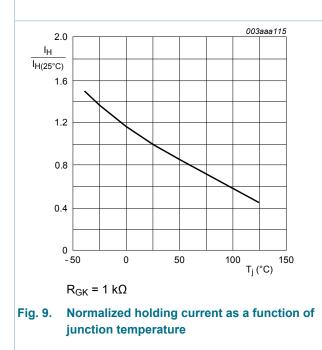
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static char	acteristics	· · · · · · · · · · · · · · · · · · ·				
I _{GT}	gate trigger current	V _D = 12 V; I _T = 10 mA; T _j = 25 °C; Fig. 7		3	12	μA
IL	latching current	V_D = 12 V; I _G = 0.5 mA; R _{GK} = 1 kΩ; T _j = 25 °C; Fig. 8	-	2	6	mA
I _H	holding current	V_D = 12 V; R _{GK} = 1 kΩ; T _j = 25 °C; Fig. 9	-	2	5	mA
V _T	on-state voltage	I _T = 1 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.2	1.35	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 10 mA; T _j = 25 °C; Fig. 11	-	0.5	0.8	V
		V _D = 400 V; I _T = 10 mA; T _j = 125 °C; <u>Fig. 11</u>	0.2	0.3	-	V
I _D	off-state current	V_D = 400 V; T_j = 125 °C; R_{GK} = 1 k Ω	-	0.05	0.1	mA
I _R	reverse current	V_R = 400 V; T _j = 125 °C; R _{GK} = 1 kΩ	-	0.05	0.1	mA
Dynamic c	haracteristics		I			
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 268 V; T _j = 125 °C; R _{GK} = 1 kΩ; (V _{DM} = 67% of V _{DRM}); exponential waveform; Fig. 12	-	150	-	V/µs
t _{gt}	gate-controlled turn-on time	I_{TM} = 2 A; V _D = 400 V; I _G = 10 mA; dI _G / dt = 0.1 A/µs; T _j = 25 °C	-	2	-	μs
t _q	commutated turn-off time	$\begin{split} &V_{DM} = 268 \text{ V; } T_{j} = 125 \text{ °C; } I_{TM} = 1.6 \text{ A;} \\ &V_{R} = 35 \text{ V; } (dI_{T}/dt)_{M} = 30 \text{ A/}\mu\text{s; } dV_{D}/\\ &dt = 2 \text{ V/}\mu\text{s; } R_{GK} = 1 \text{ k}\Omega\text{; } (V_{DM} = 67\% \text{ of } \\ &V_{DRM}) \end{split}$	-	100	-	μs

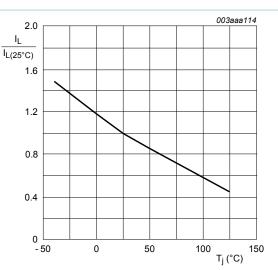
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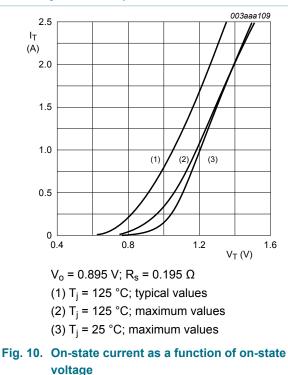






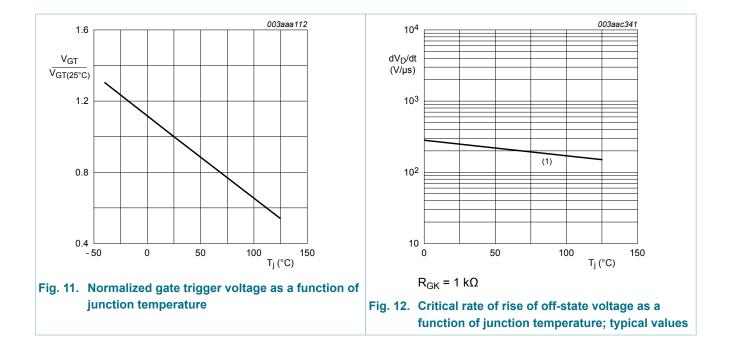
R_{GK} = 1 kΩ





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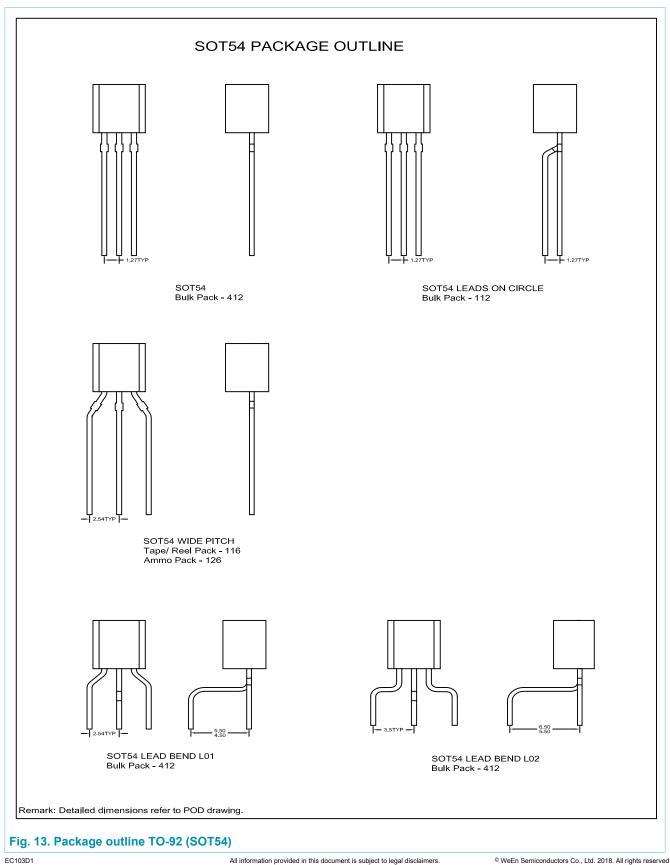
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10. Package outline



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Document status [1][2]	Product status [<u>3]</u>	Definition
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Product [short] data sheet	Production	This document contains the product specification.

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